

TLP108

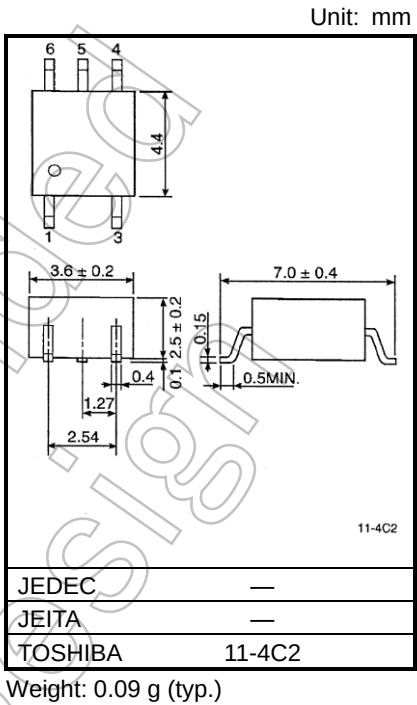
Isolated bus drivers
High speed line receivers
Microprocessor system interfaces

The Toshiba TLP108 consists of an infrared emitting diode optically coupled to a high-gain, high-speed photodetector. The TLP108 is housed in a 6-pin MFSOP. With a totem-pole output, the TLP108 is capable of both sinking and sourcing current. The TLP108 has an internal Faraday shield, which provides a guaranteed common-mode transient immunity. The TLP108 has an inverting output. A noninverting-output version, the TLP105, is also available.

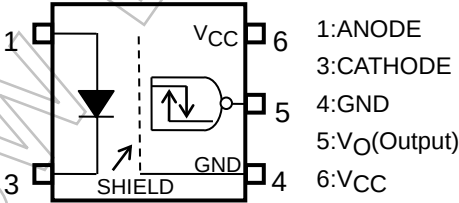
- Inverter logic type (totem-pole output)
- Guaranteed Performance Over temperature: -40 to 100°C
- Power Supply Voltage: 4.5 to 20 V
- Input Threshold Current: $I_{FHL}=1.6\text{ mA (max)}$
- Switching Time (t_{pLH}/t_{pHL}): 250 ns (max)
- Common mode transient immunity: 10 kV/ μs
- Isolation Voltage: 3750 Vrms
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service
No.5A File No.E67349
- VDE-approved: EN 60747-5-5 (Note1)
Note1 : When a VDE approved type is needed,
Please designate the **Option(V4)**.

Truth Table

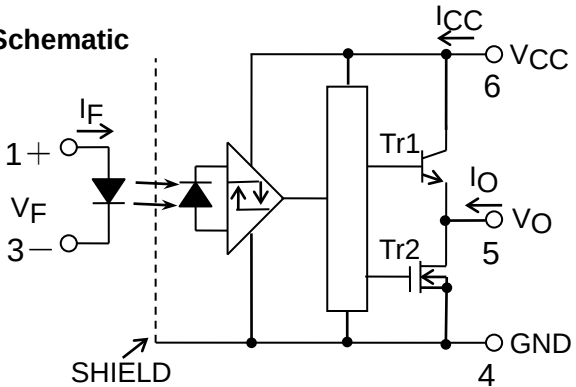
Input	LED	Tr1	Tr2	Output
H	ON	OFF	ON	L
L	OFF	ON	OFF	H



Pin Configuration (top View)



Schematic



0.1 μF bypass capacitor must be connected between pin 6 and 4.

Start of commercial production
2008-04

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Input Current , ON	$I_{F(ON)}$	2	—	10	mA
Input Voltage , OFF	$V_{F(OFF)}$	0	—	0.8	V
Supply Voltage*	V_{CC}	4.5	—	20	V
Operating Temperature	T_{opr}	-40	—	100	°C
Fan-out (TTL Load)	N	—	—	4	—

* This item denotes operating range, not meaning of recommended operating conditions.

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
LED	Forward Current	I_F	20	mA
	Forward Current Derating ($T_a \geq 83^\circ\text{C}$)	$\Delta I_F/^\circ\text{C}$	-0.48	mA/°C
	Peak Transient Forward Current (Note 1)	I_{FPT}	1	A
	Input Power Dissipation	P_D	40	mW
	Reverse Voltage	V_R	5	V
DETECTOR	Output Current 1 ($T_a \leq 25^\circ\text{C}$)	I_{O1}	25/-15	mA
	Output Current 2 ($T_a \leq 100^\circ\text{C}$)	I_{O2}	5/-5	mA
	Output Current Derating ($T_a \geq 25^\circ\text{C}$)	$\Delta I_{O1}/^\circ\text{C}$	-0.26/-0.13	mA/°C
	Peak Output Current (Note 2)	I_{OP}	50/-50	mA
	Output Voltage	V_O	-0.5 to 20	V
	Output Power Dissipation	P_O	75	mW
	Supply Voltage	V_{CC}	-0.5 to 20	V
	Operating Temperature Range	T_{opr}	-40 to 100	°C
Storage Temperature Range		T_{sta}	-55 to 125	°C
Lead Solder Temperature (10 s)		T_{sol}	260	°C
Isolation Voltage (AC, 60 s, R.H. $\leq 60\%$) (Note 3)		BV_S	3750	V_{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Pulse width $\leq 1\ \mu\text{s}$, 300 pps.

Note 2: Pulse width $\leq 5\ \mu\text{s}$, duty cycle ≤ 0.025

Note 3: Device considered a two terminal device: pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together.

Electrical Characteristics

(Unless otherwise specified, Ta = -40 to 100°C, VCC = 4.5 to 20 V)

Characteristics	Symbol	Test Circuit	Condition	Min	Typ.	Max	Unit	
Input Forward Voltage	V _F	—	I _F = 10 mA, Ta = 25 °C	1.45	1.57	1.75	V	
Temperature Coefficient of Forward Voltage	ΔV _F /ΔTa	—	I _F = 10 mA	—	-2.0	—	mV/°C	
Input Reverse Current	I _R	—	V _R = 5 V, Ta = 25 °C	—	—	10	μA	
Input Capacitance	C _T	—	V = 0 V, f = 1 MHz, Ta = 25 °C	—	100	—	pF	
Logic Low Output Voltage	V _{OL}	1	I _{OL} = 3.5 mA , I _F = 5 mA	—	0.2	0.6	V	
Logic High Output Voltage	V _{OH}	2	I _{OH} = -2.6 mA, V _F = 0.8 V	V _{CC} = 4.5 V	2.7	4.0	—	V
				V _{CC} = 20 V	17.4	19.0	—	
Logic Low Supply Current	I _{CCL}	3	I _F = 5 mA	V _{CC} = 20 V	—	—	3.0	mA
				V _{CC} = 5.5 V	—	—	3.0	
Logic High Supply Current	I _{CCH}	4	V _F = 0 V	V _{CC} = 20 V	—	—	3.0	mA
				V _{CC} = 5.5 V	—	—	3.0	
Logic Low Short Circuit Output Current (Note 1)	I _{OSL}	5	I _F = 5 mA V _O = GND	V _{CC} = V _O = 5.5 V	15	80	—	mA
				V _{CC} = V _O = 20 V	20	90	—	
Logic High Short Circuit Output Current (Note 1)	I _{OSH}	6	V _F = 0 V	V _{CC} = 5.5 V	-5	-15	—	mA
				V _{CC} = 20 V	-10	-20	—	
Input Current Logic Low Output	I _{FHL}	—	I _O = 3.5 mA, V _O < 0.4 V	—	0.4	1.6	mA	
Input Voltage Logic High Output	V _{FLH}	—	I _O = -2.6 mA, V _O > 2.4 V	0.8	—	—	V	
Input Current Hysteresis	I _{HYS}	—	V _{CC} = 5 V	—	0.05	—	mA	

*All typical values are at $T_a = 25^\circ\text{C}$

Note 1: Duration of output short circuit time should not exceed 10 ms.

Isolation Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ..	Max	Unit
Capacitance input to output	C_S	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	R.H. $\leq 60\%$, $V_S = 500 \text{ V}$	1×10^{12}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 60 s	3750	—	—	V_{rms}

Note : Device considered a two terminal device: pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together..

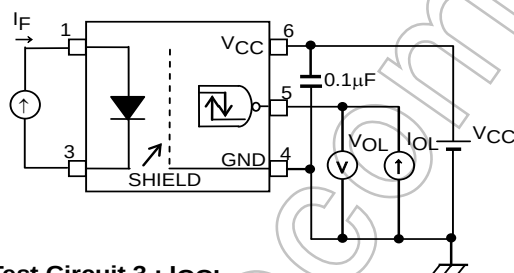
Switching Characteristics

(Unless otherwise specified, $T_a = -40$ to 100°C , $V_{CC} = 4.5$ to 20 V)

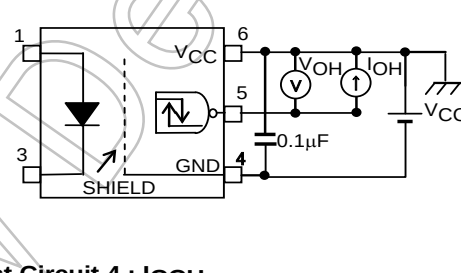
Characteristics	Symbol	Test Circuit	Condition	Min	Typ.	Max	Unit
Propagation Delay Time to Logic High output	t_{pLH}	7, 8	$I_F = 3 \rightarrow 0\text{ mA}$	30	150	250	ns
Propagation Delay Time to Logic Low output	t_{pHL}		$I_F = 0 \rightarrow 3\text{ mA}$	30	150	250	ns
Switching Time Dispersion between ON and OFF	$ t_{pHL} - t_{pLH} $		—	—	—	220	ns
Rise Time (10 – 90 %)	t_r		$I_F = 3 \rightarrow 0\text{ mA}$, $V_{CC} = 5\text{ V}$	—	30	75	ns
Fall Time (90 – 10 %)	t_f		$I_F = 0 \rightarrow 3\text{ mA}$, $V_{CC} = 5\text{ V}$	—	30	75	ns
Common Mode transient Immunity at High Level Output	CM_H	9	$V_{CM} = 1000\text{ V}_{p-p}$, $I_F = 0\text{ mA}$, $V_{CC} = 20\text{ V}$, $T_a = 25^\circ\text{C}$	-10000	—	—	$\text{V}/\mu\text{s}$
Common Mode transient Immunity at Low Level Output	CM_L		$V_{CM} = 1000\text{ V}_{p-p}$, $I_F = 5\text{ mA}$, $V_{CC} = 20\text{ V}$, $T_a = 25^\circ\text{C}$	10000	—	—	$\text{V}/\mu\text{s}$

*All typical values are at $T_a = 25^\circ\text{C}$

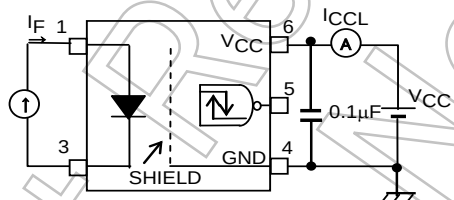
Test Circuit 1 : VOL



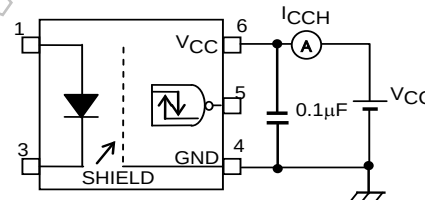
Test Circuit 2 : VOH



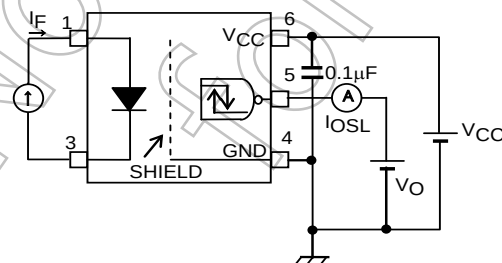
Test Circuit 3 : ICCL



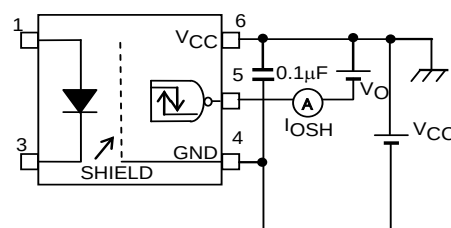
Test Circuit 4 : ICCH



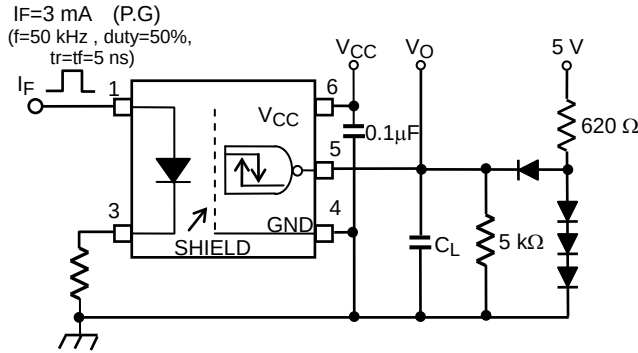
Test Circuit 5 : IOSL



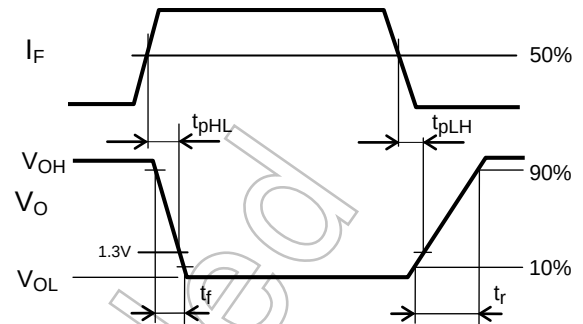
Test Circuit 6 : IOSH



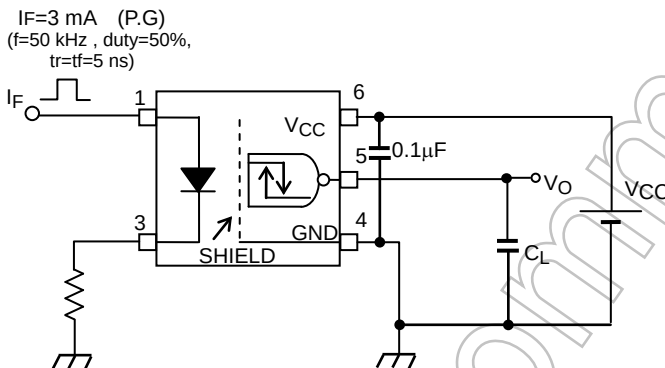
Test Circuit 7: Switching Time Test Circuit



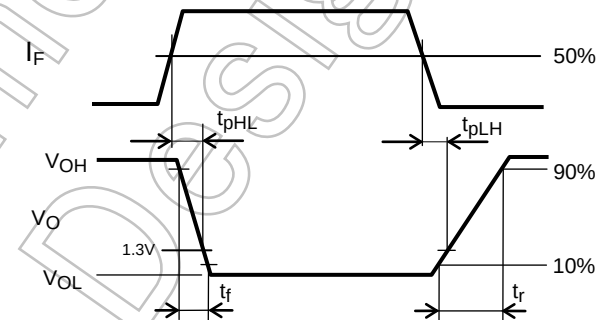
C_L is approximately 15 pF which includes probe and stray wiring capacitance.
P.G.: Pulse generator



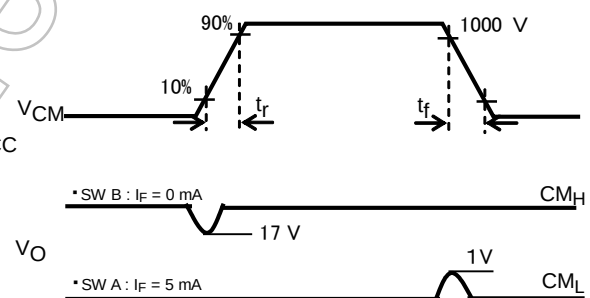
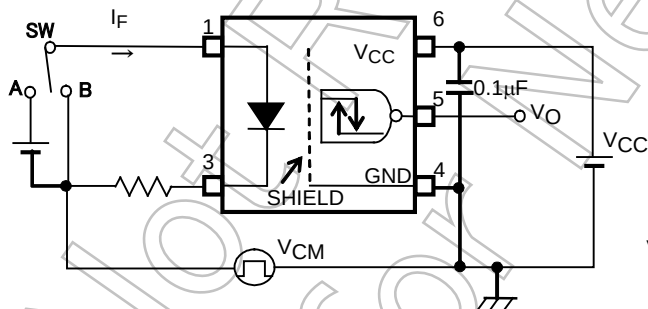
Test Circuit 8: Switching Time Test Circuit



C_L is approximately 15 pF which includes probe and stray wiring capacitance.
P.G.: Pulse generator



Test Circuit 9: Common Mode Transient Immunity Test Circuit



$$CM_H = \frac{800(V)}{t_f (\mu s)} \quad CM_L = \frac{800(V)}{t_r (\mu s)}$$

RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA".

Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- **PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").** Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. **IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.** For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- **ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.**
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**